TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK3857TK

For ECM

· Application for Ultra-compact ECM

Absolute Maximum Ratings (Ta=25°C)

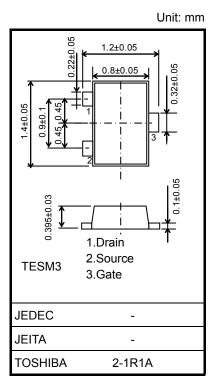
Characteristic	Symbol	Rating	Unit	
Gate-Drain voltage	V_{GDO}	-20	V	
Gate Current	IG	10	mA	
Drain power dissipation (Ta = 25°C)	P _D	100	mW	
Junction Temperature	Tj	125	°C	
Storage temperature range	T _{stg}	-55~125	°C	

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

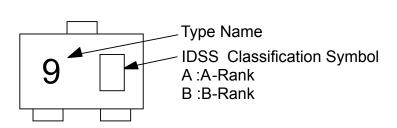


Weight: 2.2mg (typ.)

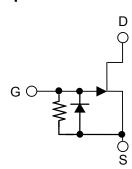
IDSS CLASSIFICATION

A-Rank 140~240μA B-Rank 210~350μA

Marking



Equivalent Circuit





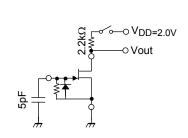
Electrical Characteristics (Ta=25°C)

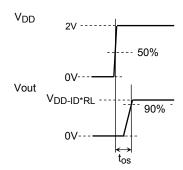
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain Current	I _{DSS}	$V_{DS}=2\ V,\ V_{GS}=0$	140	_	350	μΑ
Drain Current	ΙD	$V_{DD} = 2 \text{ V, RL} = 2.2 \text{k}\Omega, \text{Cg} = 5 \text{pF}$	_	_	370	μA
Gate-Source Cut-off Voltage	V _{GS(OFF)}	$V_{DS} = 2 \text{ V}, I_D = 1 \mu A$	-0.1	_	-1.0	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 2 V, V_{GS} = 0V$	0.9	1.3	_	mS
Gate-Drain Voltage	V _{(BR)GDO}	IG=-10μA	-20	_	_	V
Input capacitance	C _{iss}	$V_{DS} = 2 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	3.5	_	pF
Voltage Gain	Gv	$V_{DD} = 2V$, RL= 2.2k Ω ,Cg = 5pF, f = 1kHz,vin=100mV	-3.0	-0.5	_	dB
Delta Voltage Gain	DGv(f)	$V_{DD} = 2V$, RL= 2.2k Ω ,Cg = 5pF,f = 1kHz to 100Hz,vin=100mV	_	0	-1	dB
Delta Voltage Gain	DGv(V)	$V_{DD} = 2V$ to 1.5V, RL= 2.2k Ω ,Cg = 5pF,f = 1kHz, vin=100mV	_	-0.8	-2	dB
Noise Voltage	VN	$V_{DD} = 2V$, RL= 1k Ω ,Cg = 10pF,Gv=80dB, A-Curve Filter	_	25	55	mV
Total Harmonic Distortion	THD	$V_{DD} = 2V$, RL= 2.2k Ω ,Cg = 5pF, f = 1kHz, vin=50mV	_	0.7	_	%
Time Output Stability	tos	$V_{DD} = 2V$, RL= 2.2k Ω ,Cg = 5pF		100	200	ms

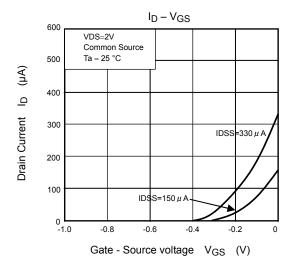
Time Output Stability Test Method

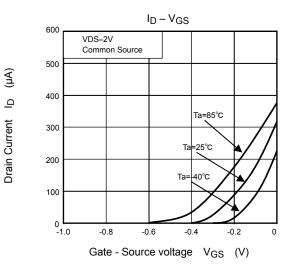
a) TEST CIRCUIT

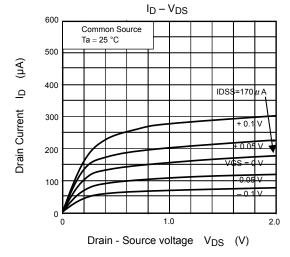
b) TEST SIGNAL

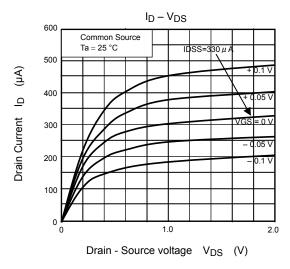


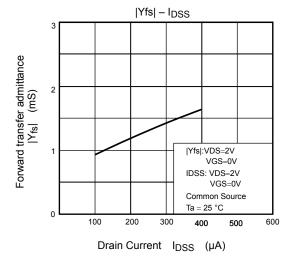


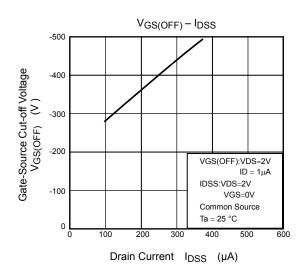


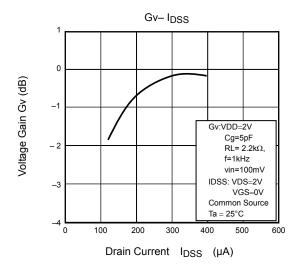


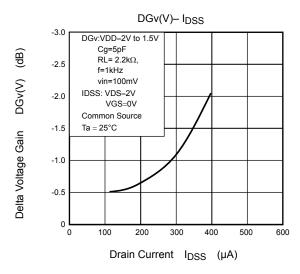


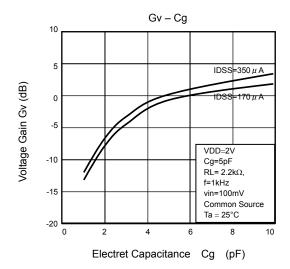


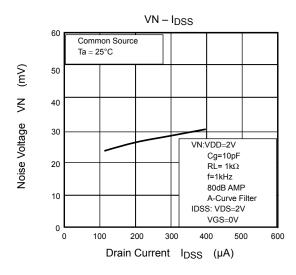


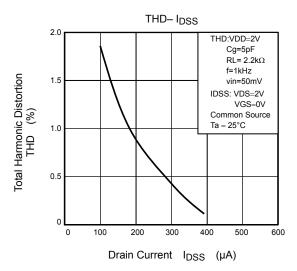


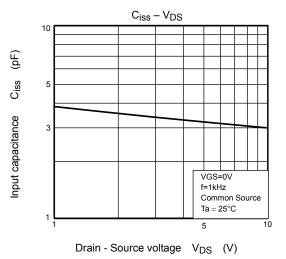












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20070701-EN GENERAL

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